

# XP161A0390PR



Power MOS FET

- ◆N-Channel Power MOS FET
- ◆DMOS Structure
- ◆Low On-State Resistance: 0.09Ω (max)
- ◆Ultra High-Speed Switching
- ◆SOT-89 Package

## General Description

The XP161A0390PR is an N-Channel Power MOS FET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOT-89 package makes high density mounting possible.

## Applications

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

## Features

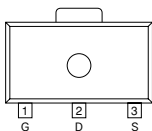
**Low on-state resistance :**  $R_{ds(on)}=0.09\Omega(V_{gs}=4.5V)$   
 $R_{ds(on)}=0.13\Omega(V_{gs}=2.5V)$   
 $R_{ds(on)}=0.3\Omega(V_{gs}=1.5V)$

**Ultra high-speed switching**

**Operational Voltage :** 1.5V

**High density mounting :** SOT-89

## Pin Configuration



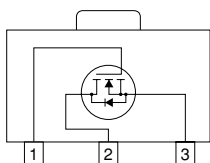
SOT-89  
(TOP VIEW)

## Pin Assignment

PIN NUMBER	PIN NAME	FUNCTION
1	G	Gate
2	D	Drain
3	S	Source

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## Equivalent Circuit



N-Channel MOS FET  
(1 device built-in)

## Absolute Maximum Ratings

Ta=25°C			
PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	20	V
Gate-Source Voltage	Vgss	±8	V
Drain Current (DC)	Id	3	A
Drain Current (Pulse)	Idp	9	A
Reverse Drain Current	Idr	3	A
Continuous Channel Power Dissipation (note)	Pd	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55~150	°C

Note: When implemented on a ceramic PCB

## Electrical Characteristics

### DC Characteristics

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Drain Cut-off Current	Idss	Vds=20V, Vgs=0V			10	μA
Gate-Source Leakage Current	Igss	Vgs=±8V, Vds=0V			±10	μA
Gate-Source Cut-off Voltage	Vgs(off)	Id=1mA, Vds=10V	0.5			V
Drain-Source On-state Resistance (note)	Rds(on)	Id=1.5A, Vgs=4.5V		0.07	0.09	Ω
		Id=1.5A, Vgs=2.5V		0.1	0.13	Ω
		Id=1.5A, Vgs=1.5V		0.17	0.3	Ω
Forward Transfer Admittance (note)	Yfs	Id=1.5A, Vds=10V		6		S
Body Drain Diode Forward Voltage	Vf	If=3A, Vgs=0V		0.85	1.1	V

Note: Effective during pulse test.

### Dynamic Characteristics

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Capacitance	Ciss	Vds=10V, Vgs=0V f=1MHz		380		pF
Output Capacitance	Coss			170		pF
Feedback Capacitance	Crss			60		pF

### Switching Characteristics

Ta=25°C

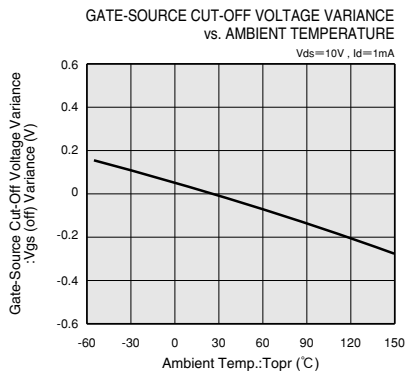
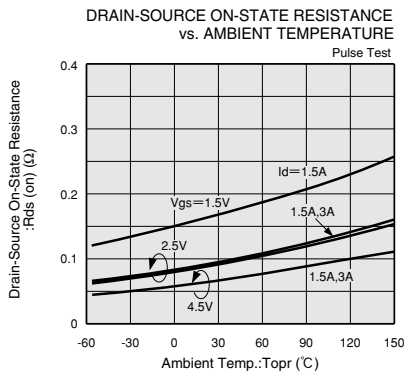
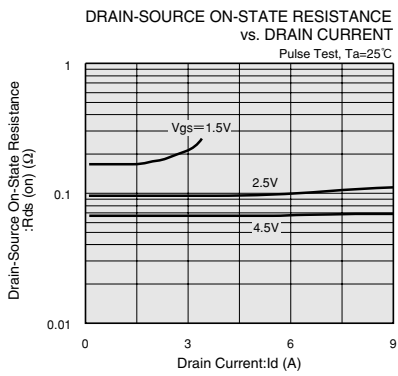
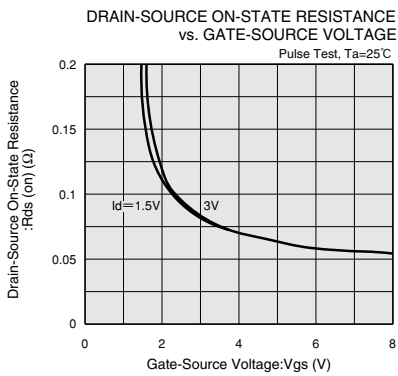
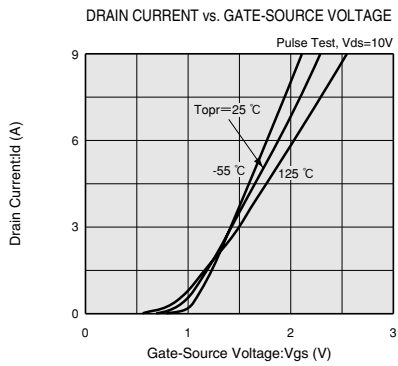
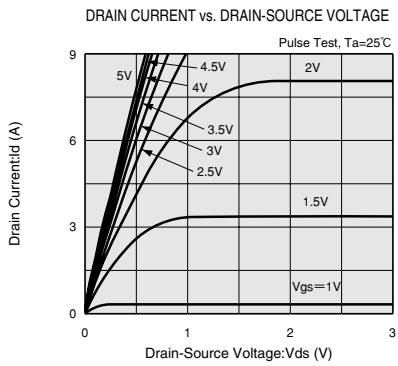
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Turn-on Delay Time	td (on)	Vgs=5V, Id=1.5A Vdd=10V		10		ns
Rise Time	tr			15		ns
Turn-off Delay Time	td (off)			70		ns
Fall Time	tf			40		ns

### Thermal Characteristics

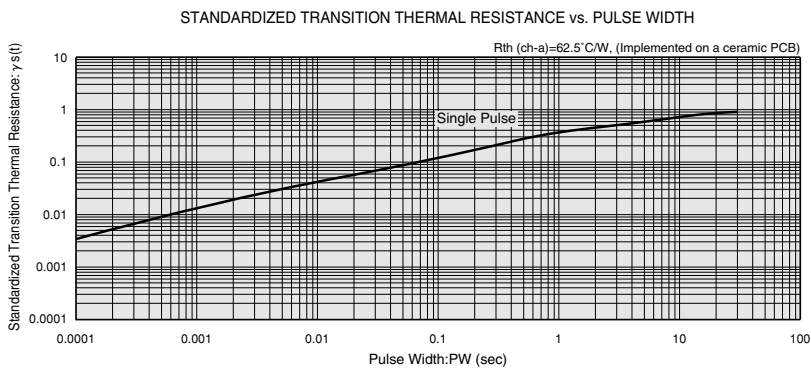
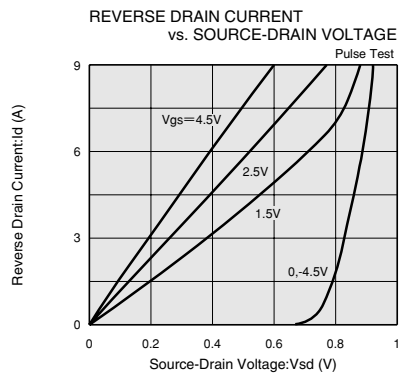
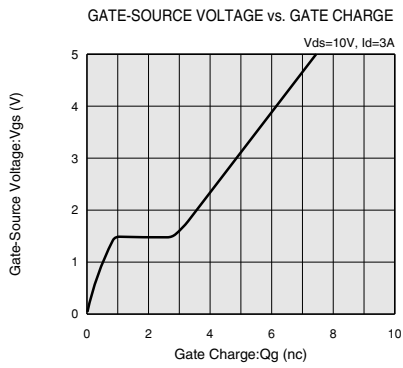
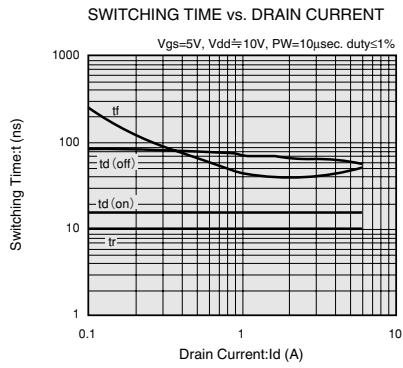
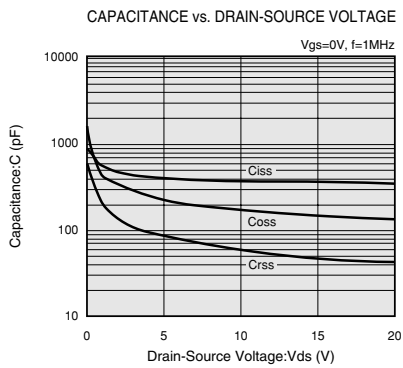
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Thermal Resistance (channel-ambience)	Rth (ch-a)	Implement on a ceramic PCB		62.5		°C/W

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## Typical Performance Characteristics



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